DATA SHEET

<div style="border:2px solid red">

For a complete data sheet, please also download:

- The IC04 LOCMOS HE4000B Logic
  Family Specifications HEF, HEC
- The IC04 LOCMOS HE4000B Logic
  Package Outlines/Information HEF, HEC

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HEF4011B
gates
Quadruple 2-input NAND gate

Product specification   January 1995

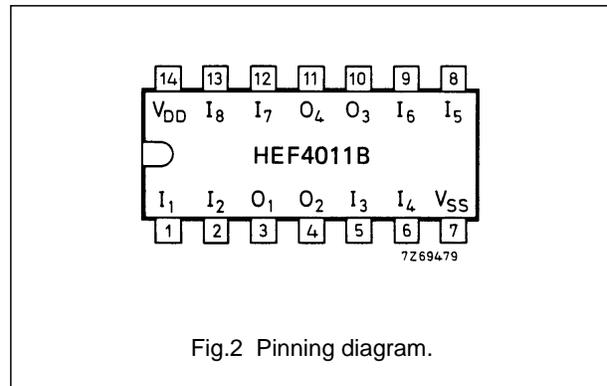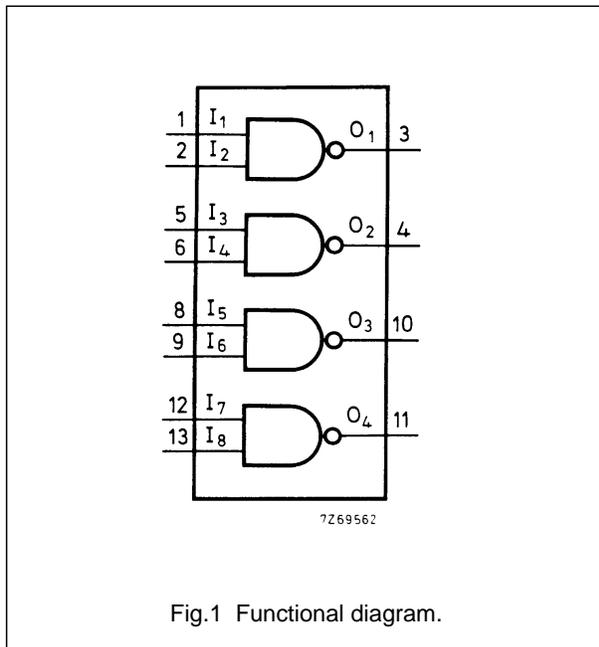File under Integrated Circuits, IC04

Philips
**Semiconductors**

PHILIPS

Quadruple 2-input NAND gate

HEF4011B gates

DESCRIPTION

The HEF4011B provides the positive quadruple 2-input NAND function. The outputs are fully buffered for highest noise immunity and pattern insensitivity of output impedance.

Fig.1 Functional diagram.

Fig.2 Pinning diagram.

HEF4011BP(N):   14-lead DIL; plastic (SOT27-1)

HEF4011BD(F):   14-lead DIL; ceramic (cerdip) (SOT73)

HEF4011BT(D):   14-lead SO; plastic (SOT108-1)

( ): Package Designator North America

Fig.3 Logic diagram (one gate).
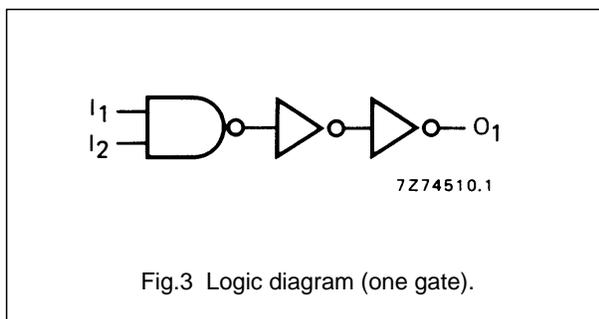
FAMILY DATA, I_{DD} LIMITS category GATES

See Family Specifications

Quadruple 2-input NAND gate

AC CHARACTERISTICS

V_{SS} = 0 V; T_{amb} = 25 °C; C_L = 50 pF; input transition times ≤ 20 ns

	V_{DD} V	SYMBOL	TYP	MAX		TYPICAL EXTRAPOLATION FORMULA
Propagation delays	5		55	110	ns	28 ns + (0,55 ns/pF) C_L
$I_n \rightarrow O_n$	10	t_{PHL}; t_{PLH}	25	45	ns	14 ns + (0,23 ns/pF) C_L
	15		20	35	ns	12 ns + (0,16 ns/pF) C_L
Output transition times	5		60	120	ns	10 ns + (1,0 ns/pF) C_L
HIGH to LOW	10	t_{THL}	30	60	ns	9 ns + (0,42 ns/pF) C_L
	15		20	40	ns	6 ns + (0,28 ns/pF) C_L
	5		60	120	ns	10 ns + (1,0 ns/pF) C_L
LOW to HIGH	10	t_{TLH}	30	60	ns	9 ns + (0,42 ns/pF) C_L
	15		20	40	ns	6 ns + (0,28 ns/pF) C_L

	V_{DD} V	TYPICAL FORMULA FOR P (μW)	
Dynamic power	5	1300 f_i + Σ ($f_o C_L$) × V_{DD}^2	where
dissipation per	10	6000 f_i + Σ ($f_o C_L$) × V_{DD}^2	f_i = input freq. (MHz)
package (P)	15	20 100 f_i + Σ ($f_o C_L$) × V_{DD}^2	f_o = output freq. (MHz)
			C_L = load capacitance (pF)
			Σ ($f_o C_L$) = sum of outputs
			V_{DD} = supply voltage (V)